



BUK7K35-60E

Dual N-channel 60 V, 30 mΩ standard level MOSFET

15 November 2013

Product data sheet

1. General description

Dual standard level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Dual MOSFET
- Q101 compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with $V_{GS(th)}$ of greater than 1 V at 175 °C

3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|----------------------------------|--|-----|-----|------|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}; T_j \leq 175\text{ °C}$ | - | - | 60 | V |
| I_D | drain current | $V_{GS} = 10\text{ V}; T_{mb} = 25\text{ °C}; \text{Fig. 1}$ | - | - | 20.7 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}; \text{Fig. 2}$ | - | - | 38 | W |
| Static characteristics FET1 and FET2 | | | | | | |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 10\text{ V}; I_D = 5\text{ A}; T_j = 25\text{ °C}; \text{Fig. 11}$ | - | 24 | 30 | mΩ |
| Dynamic characteristics FET1 and FET2 | | | | | | |
| Q_{GD} | gate-drain charge | $I_D = 5\text{ A}; V_{DS} = 48\text{ V}; V_{GS} = 10\text{ V}; T_j = 25\text{ °C}; \text{Fig. 14}; \text{Fig. 13}$ | - | 4.7 | - | nC |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|---|---|
| 1 | S1 | source1 |  <p>LFPAK56D (SOT1205)</p> |  <p>mbk725</p> |
| 2 | G1 | gate1 | | |
| 3 | S2 | source2 | | |
| 4 | G2 | gate2 | | |
| 5 | D2 | drain2 | | |
| 6 | D2 | drain2 | | |
| 7 | D1 | drain1 | | |
| 8 | D1 | drain1 | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|----------|--|---------|
| | Name | Description | Version |
| BUK7K35-60E | LFPAK56D | Plastic single ended surface mounted package (LFPAK56D); 8 leads | SOT1205 |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| BUK7K35-60E | 73560E |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|---|-----|------|------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}$; $T_j \leq 175\text{ °C}$ | - | 60 | V |
| V_{DGR} | drain-gate voltage | $R_{GS} = 20\text{ k}\Omega$ | - | 60 | V |
| V_{GS} | gate-source voltage | $T_j \leq 175\text{ °C}$; DC | -20 | 20 | V |
| I_D | drain current | $T_{mb} = 25\text{ °C}$; $V_{GS} = 10\text{ V}$; Fig. 1 | - | 20.7 | A |
| | | $T_{mb} = 100\text{ °C}$; $V_{GS} = 10\text{ V}$; Fig. 1 | - | 17 | A |
| I_{DM} | peak drain current | $T_{mb} = 25\text{ °C}$; pulsed; $t_p \leq 10\text{ }\mu\text{s}$; Fig. 4 | - | 95 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25\text{ °C}$; Fig. 2 | - | 38 | W |

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---|--|---|--------|------|---------|
| T _{stg} | storage temperature | | -55 | 175 | °C |
| T _j | junction temperature | | -55 | 175 | °C |
| Source-drain diode FET1 and FET2 | | | | | |
| I _S | source current | T _{mb} = 25 °C | - | 20.7 | A |
| I _{SM} | peak source current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C | - | 95 | A |
| Avalanche Ruggedness FET1 and FET2 | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I _D = 20.7 A; V _{sup} ≤ 60 V; V _{GS} = 10 V; T _{j(init)} = 25 °C; Fig. 3 | [1][2] | - | 20.3 mJ |

- [1] Refer to application note AN10273 for further information
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C

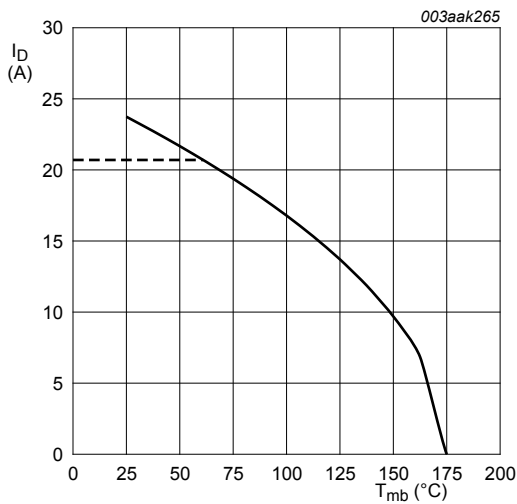


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \geq 10V$$

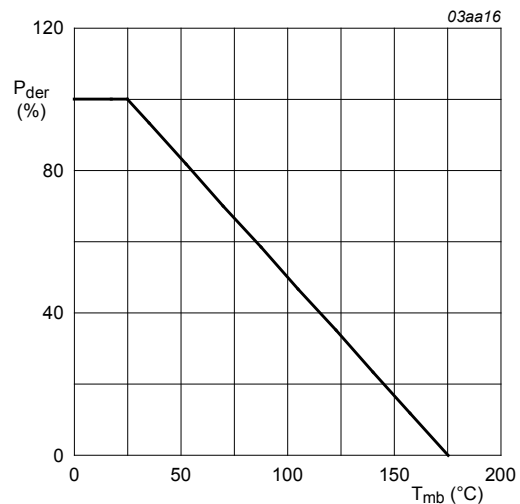


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ C)}} \times 100\%$$

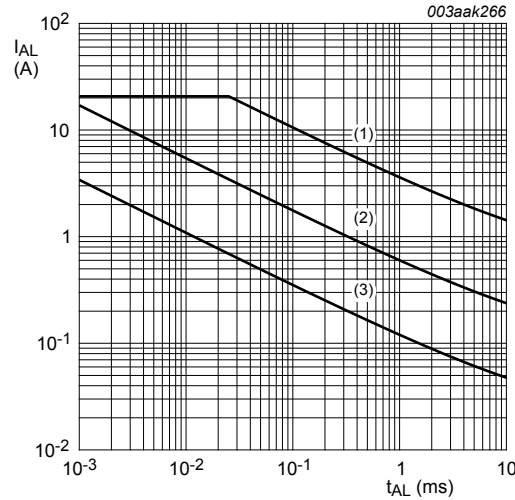


Fig. 3. Avalanche rating; avalanche current as a function of avalanche time

(1) $T_{j (init)} = 25^\circ C$; (2) $T_{j (init)} = 150^\circ C$; (3) Repetitive Avalanche

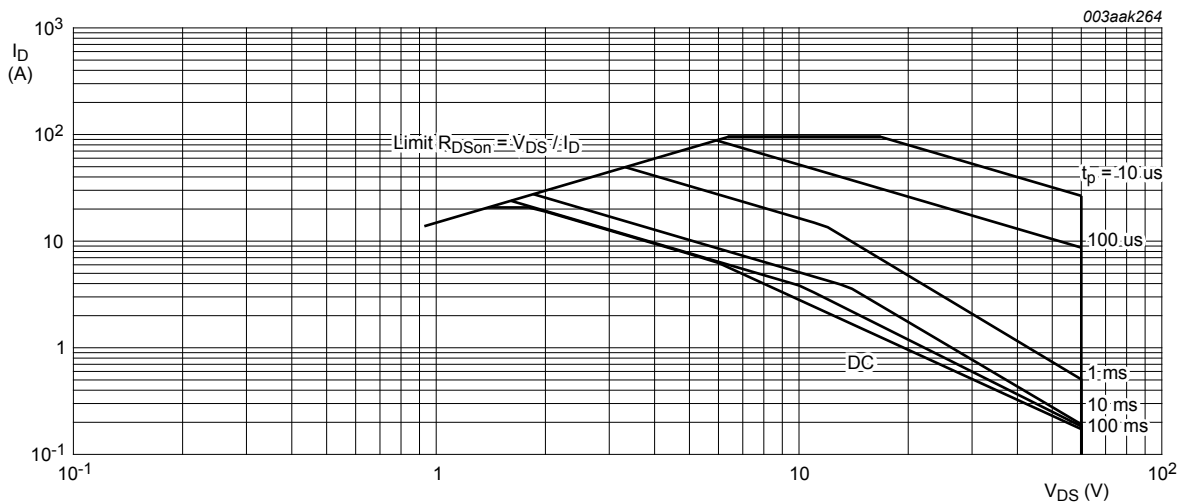


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^\circ C$; I_{DM} is a single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|---|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5 | - | - | 3.96 | K/W |
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | Minimum footprint; mounted on a printed circuit board | - | 95 | - | K/W |

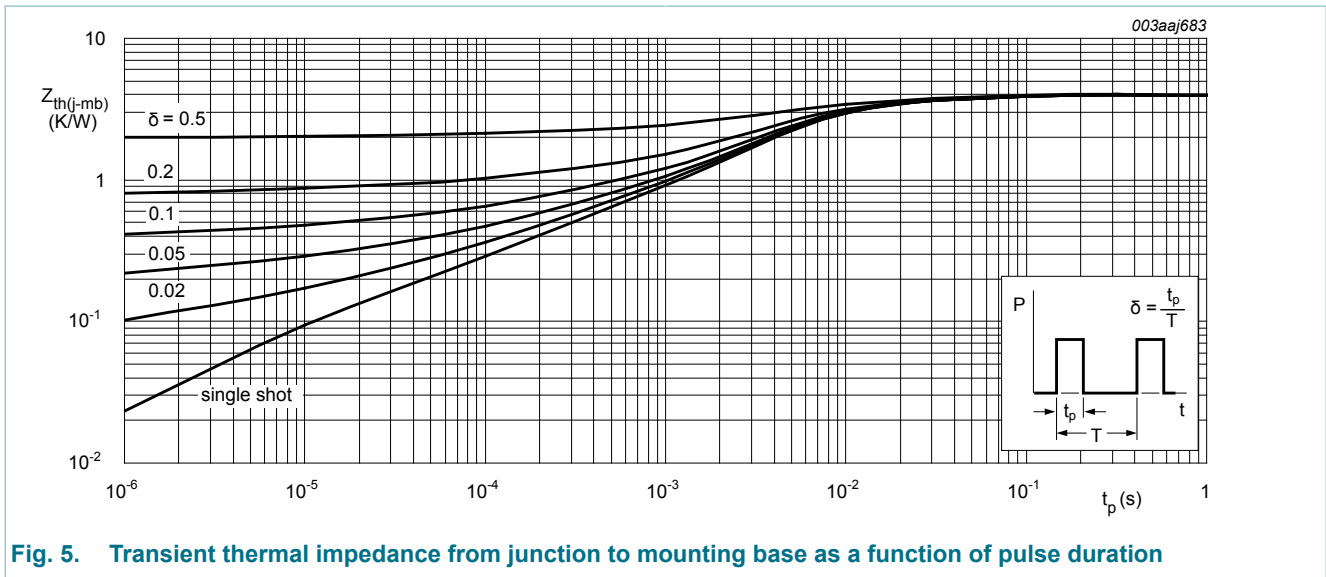


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|----------------------------------|---|-----|------|-----|---------|
| Static characteristics FET1 and FET2 | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$ | 54 | - | - | V |
| | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | 60 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ C;$ Fig. 9; Fig. 10 | 2.4 | 3 | 4 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ }^\circ C;$ Fig. 9; Fig. 10 | 1 | - | - | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ }^\circ C;$ Fig. 9; Fig. 10 | - | - | 4.5 | V |
| I_{DSS} | drain leakage current | $V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 0.02 | 1 | μA |
| | | $V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ }^\circ C$ | - | - | 500 | μA |
| I_{GSS} | gate leakage current | $V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 2 | 100 | nA |
| | | $V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ }^\circ C$ | - | 2 | 100 | nA |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 25 \text{ }^\circ C;$ Fig. 11 | - | 24 | 30 | mΩ |
| | | $V_{GS} = 10 \text{ V}; I_D = 5 \text{ A}; T_j = 175 \text{ }^\circ C;$ Fig. 12; Fig. 11 | - | 54 | 67 | mΩ |
| Dynamic characteristics FET1 and FET2 | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 5 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ }^\circ C;$ Fig. 13; Fig. 14 | - | 12.5 | - | nC |
| Q_{GS} | gate-source charge | $I_D = 5 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ }^\circ C;$ Fig. 14; Fig. 13 | - | 2.8 | - | nC |
| Q_{GD} | gate-drain charge | | - | 4.7 | - | nC |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|------------------------------|---|-----|------|-----|------|
| $V_{GS(pl)}$ | gate-source plateau voltage | $I_D = 5\text{ A}$; $V_{DS} = 48\text{ V}$; $T_j = 25\text{ °C}$; Fig. 14 ; Fig. 13 | - | 4.9 | - | V |
| C_{iss} | input capacitance | $V_{GS} = 0\text{ V}$; $V_{DS} = 25\text{ V}$; $f = 1\text{ MHz}$; $T_j = 25\text{ °C}$; Fig. 15 | - | 596 | 794 | pF |
| C_{oss} | output capacitance | | - | 97 | 117 | pF |
| C_{rss} | reverse transfer capacitance | | - | 67 | 92 | pF |
| $t_{d(on)}$ | turn-on delay time | $V_{DS} = 48\text{ V}$; $R_L = 10\text{ }\Omega$; $V_{GS} = 10\text{ V}$; $R_{G(ext)} = 5\text{ }\Omega$; $T_j = 25\text{ °C}$; $I_D = 5\text{ A}$ | - | 5.2 | - | ns |
| t_r | rise time | | - | 7 | - | ns |
| $t_{d(off)}$ | turn-off delay time | | - | 10 | - | ns |
| t_f | fall time | | - | 7.2 | - | ns |
| Source-drain diode FET1 and FET2 | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 5\text{ A}$; $V_{GS} = 0\text{ V}$; $T_j = 25\text{ °C}$; Fig. 16 | - | 0.8 | 1.2 | V |
| t_{rr} | reverse recovery time | $I_S = 5\text{ A}$; $di_S/dt = -100\text{ A}/\mu\text{s}$; $V_{GS} = 0\text{ V}$; $V_{DS} = 30\text{ V}$; $T_j = 25\text{ °C}$ | - | 18.5 | - | ns |
| Q_r | recovered charge | | - | 15.2 | - | nC |

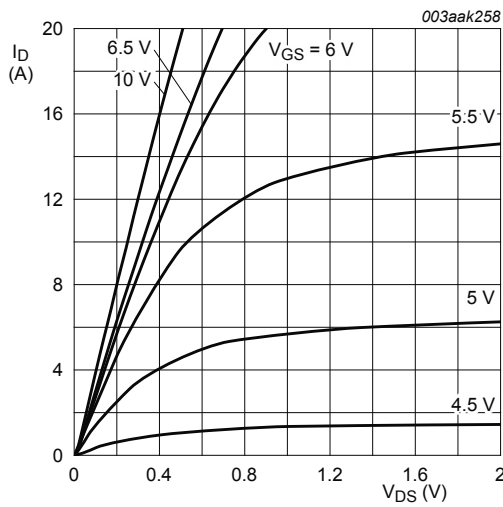


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

$T_j = 25\text{ °C}$

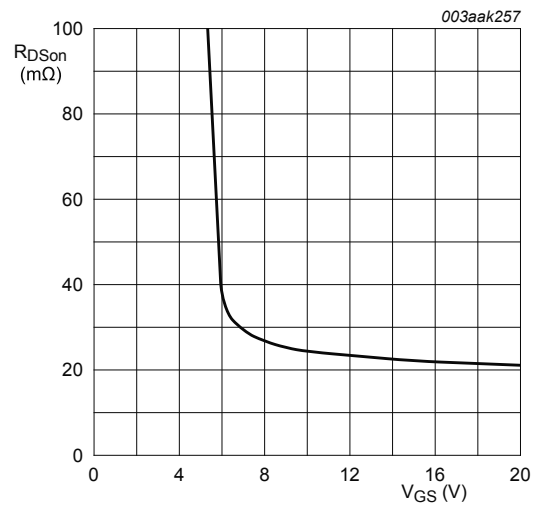


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25\text{ °C}$; $I_D = 5\text{ A}$

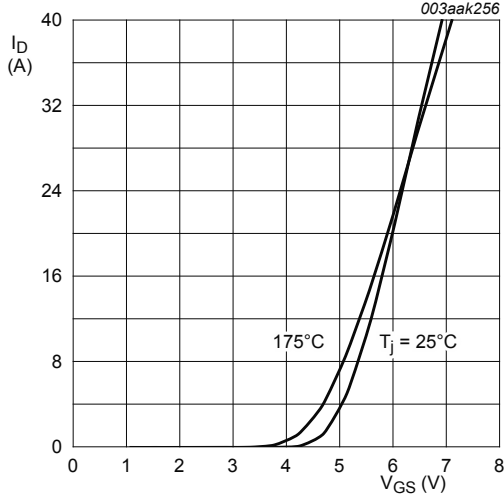


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

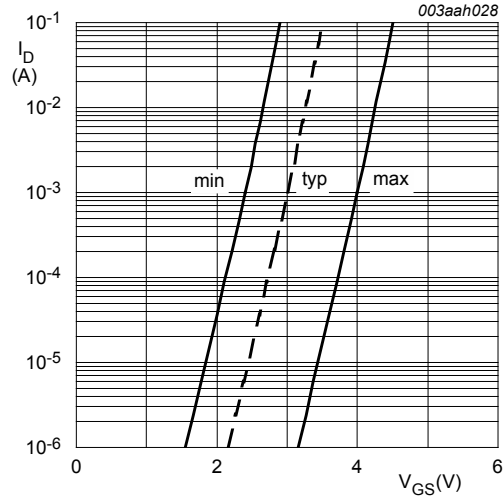


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^\circ C; V_{DS} = 5V$$

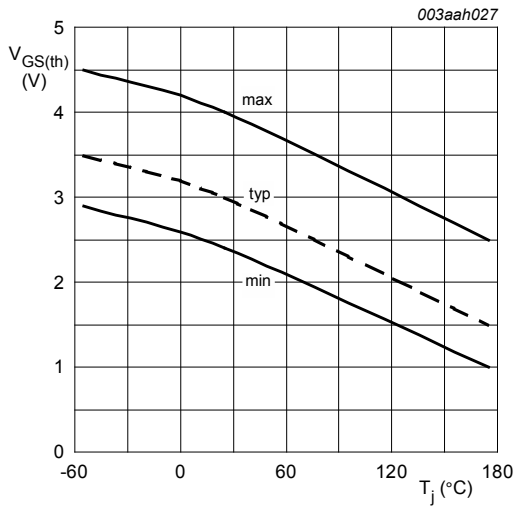


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$$

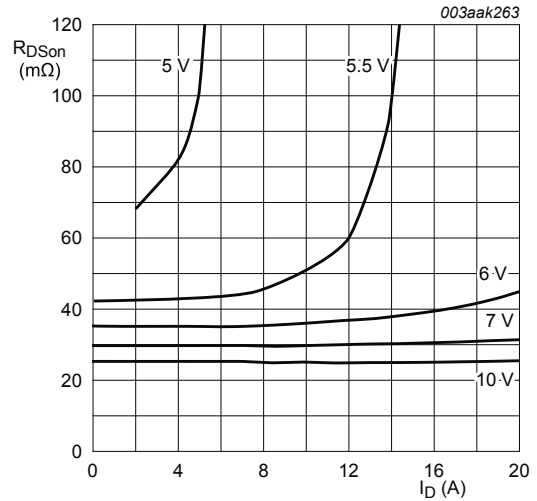


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^\circ C$$

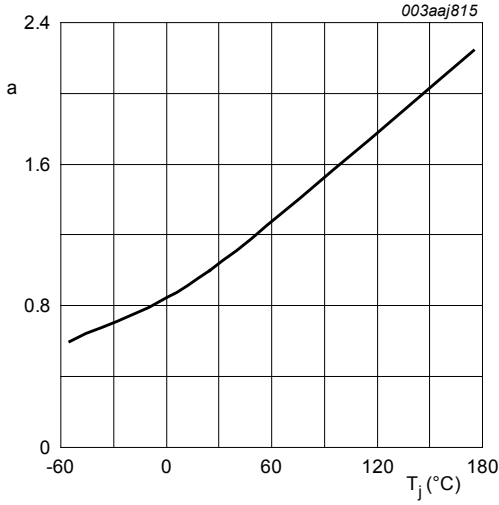


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DS(on)}}{R_{DS(on)}(25^\circ\text{C})}$$

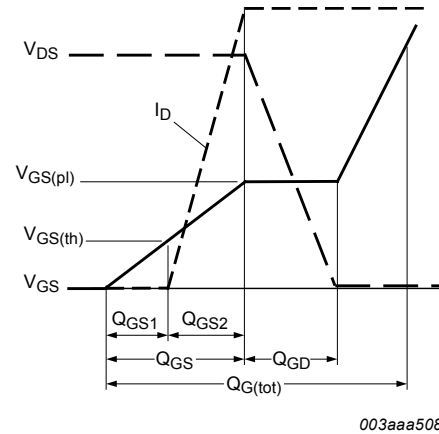


Fig. 13. Gate charge waveform definitions

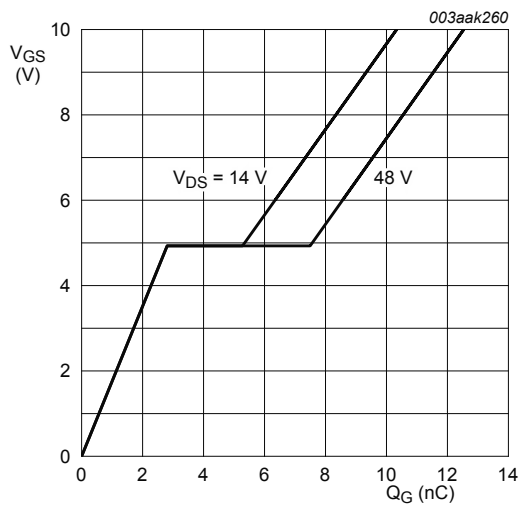


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^\circ\text{C}; I_D = 5\text{A}$$

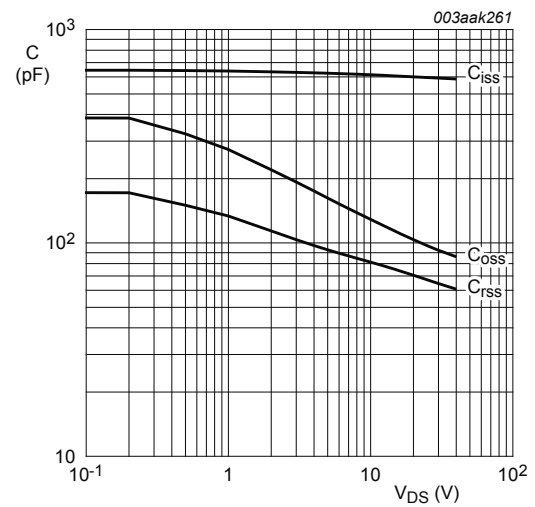


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{V}; f = 1\text{MHz}$$

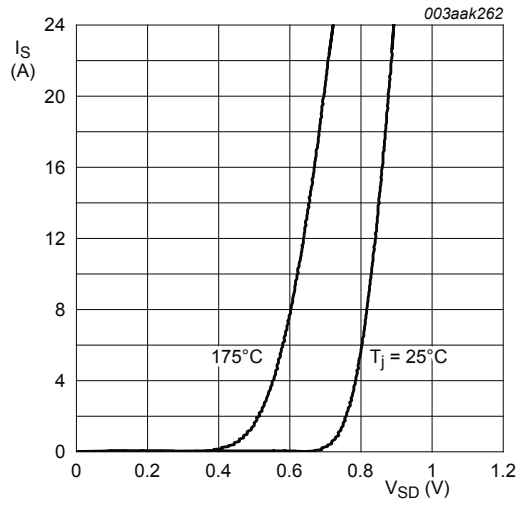


Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0V$$

11. Package outline

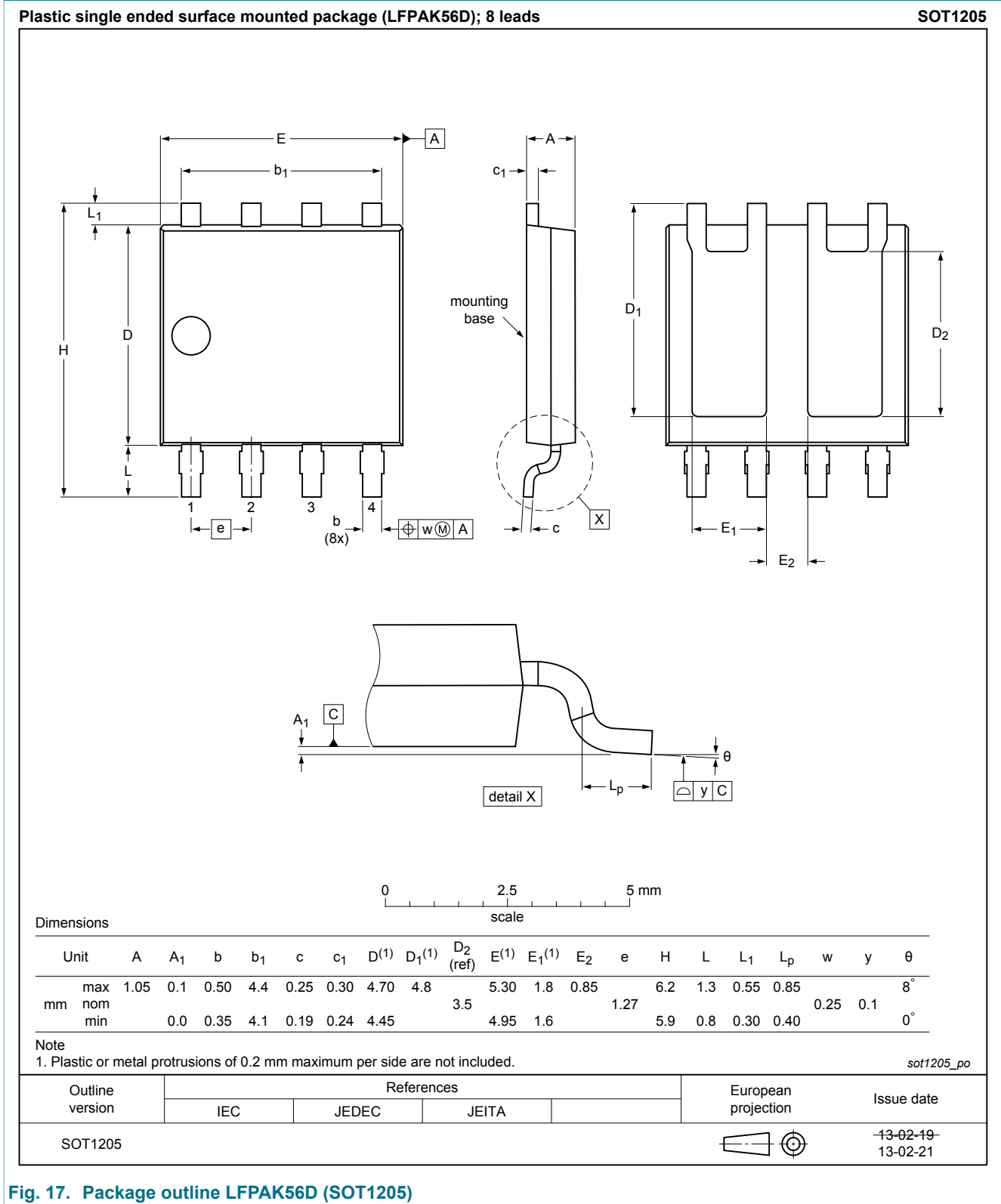


Fig. 17. Package outline LPAK56D (SOT1205)

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12.1 Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
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13. Contents

| | | |
|------|-------------------------------|----|
| 1 | General description | 1 |
| 2 | Features and benefits | 1 |
| 3 | Applications | 1 |
| 4 | Quick reference data | 1 |
| 5 | Pinning information | 2 |
| 6 | Ordering information | 2 |
| 7 | Marking | 2 |
| 8 | Limiting values | 2 |
| 9 | Thermal characteristics | 4 |
| 10 | Characteristics | 5 |
| 11 | Package outline | 10 |
| 12 | Legal information | 11 |
| 12.1 | Data sheet status | 11 |
| 12.2 | Definitions | 11 |
| 12.3 | Disclaimers | 11 |
| 12.4 | Trademarks | 12 |

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